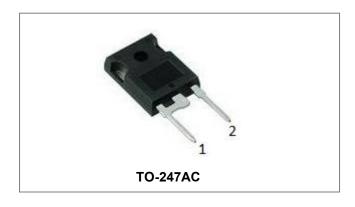


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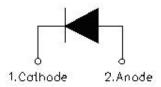
## SDUR6020W ULTRAFAST RECTIFIER



# **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### **Circuit Diagram**



#### **Features**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	200	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=85°C, rectangular wave form	60	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	650	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 60A, Pulse, T <sub>J</sub> = 25°C	-	1.08	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$	-	40	μA
	I <sub>R2</sub>	$@V_R = \text{ rated } V_R$ $T_J = 125^{\circ}C$	-	1.1	mA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	-	50	ns

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com
     sales@ smc-diodes.com



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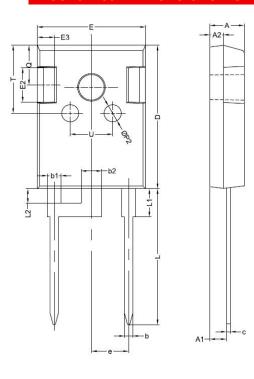


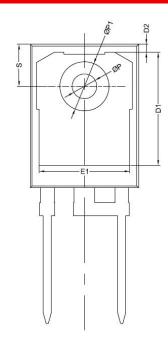


## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	$T_{stg}$	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.75	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

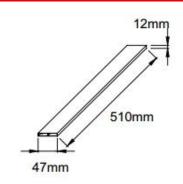
## **Mechanical Dimensions TO-247AC**





CVMPOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A1	2.20	2.41	2.61	
A2	1.90	2.00	2.10	
b	1.00	1.20	1.40	
b1	1.80	2.00	2.20	
b2	2.80	3.00	3.20	
С	0.50	0.60	0.75	
D	20.30	21.00	21.20	
D1		16.55		
D2		1.20		
E	15.45	15.8	16.0	
E1		13.30		
E2		5.00		
E3		2.50		
e		5.44		
L	19.42	19.92	20.42	
L1		4.13		
L2		2.15		
Р	3.50	3.60	3.70	
P1	7.1	_	7.40	
P2		2.50		
Q		5.80		
S T	6.05	6.15	6.25	
Т		10.00		
U		6.20		

## **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

 SDUR
 = Device Type

 60
 = Forward Current (60A)

 20
 = Reverse Voltage (200V)

 W
 = Configuration

 SSG
 = SSG

W = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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#### **Ordering Information**

Device	Package	Shipping	
SDUR6020W	TO-247AC(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

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